2.5-V 460-kbps RS-232 TRANSCEIVER WITH ±15-kV ESD PROTECTION

Check for Samples: MAX3318E

FEATURES

- **ESD Protection for RS-232 I/O Pins**
  - **±15 kV (Human-Body Model)**
  - **±8 kV (IEC 61000-4-2, Contact Discharge)**
  - **±15 kV (IEC 61000-4-2, Air-Gap Discharge)**
- **300-μA Operating Supply Current**
- **1-μA Low-Power Standby (With Receivers Active) Mode**
- **Designed to Transmit at a Data Rate of 460 kbps**
- **Auto-Power-Down Plus Option Features Flexible Power-Saving Mode**
- **Operates From a Single 2.25-V to 3-V V_{CC} Supply**

APPLICATIONS

- **Battery-Powered Systems**
- **PDAs**
- **Cellular Phones**
- **Notebooks**
- **Hand-Held Equipment**
- **Pagers**

DESCRIPTION

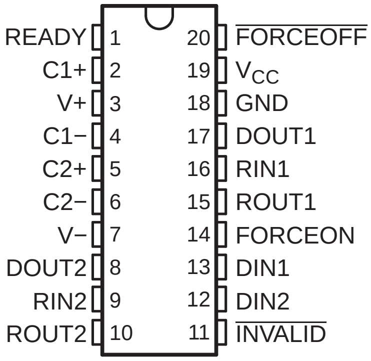
The MAX3318E is a dual-driver, dual-receiver, RS-232-compatible transceiver. The device features auto-power-down plus and enhanced electrostatic discharge (ESD) protection integrated into the chip. Driver output and receiver input are protected to ±15 kV using the IEC 61000-4-2 Air-Gap Discharge method, ±8 kV using the IEC 61000-4-2 Contact Discharge method, and ±15 kV using the Human-Body Model (HBM).

The device operates at a data rate of 460 kbps. The transceiver has a proprietary low-dropout driver output stage, enabling RS-232-compatible operation from a 2.25-V to 3-V supply with a dual charge pump. The charge pump requires only four 0.1-μF capacitors and features a logic-level output (READY) that asserts when the charge pump is regulating and the device is ready to begin transmitting.

The MAX3318E achieves a 1-μA supply current using the auto-power-down feature. This device automatically enters a low-power power-down mode when the RS-232 cable is disconnected or the drivers of the connected peripherals are inactive for more than 30 s. The device turns on again when it senses a valid transition at any driver or receiver input. Auto power down saves power without changes to the existing BIOS or operating system.

This device is available in two space-saving packages: 20-pin SSOP and 20-pin TSSOP.

**DB OR PW PACKAGE
(TOP VIEW)**



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

DETAILED DESCRIPTION

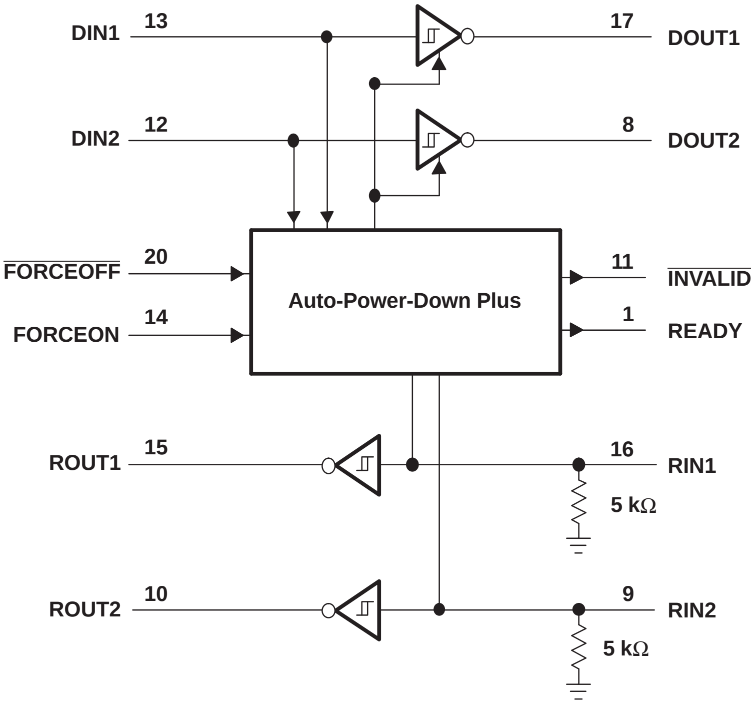
Flexible control options for power management are featured when the serial port and driver inputs are inactive. The auto-power-down plus feature functions when FORCEON is low and $\overline{\text{FORCEOFF}}$ is high. During this mode of operation, if the device does not sense valid signal transitions on all receiver and driver inputs for approximately 30 s, the built-in charge pump and drivers are powered down, reducing the supply current to 1 μA. By disconnecting the serial port or placing the peripheral drivers off, auto-power-down plus can be disabled when FORCEON and $\overline{\text{FORCEOFF}}$ are high. With auto-power-down plus enabled, the device activates automatically when a valid signal is applied to any receiver or driver input. $\overline{\text{INVALID}}$ is high (valid data) if any receiver input voltage is greater than 2.7 V or less than –2.7 V, or has been between –0.3 V and 0.3 V for less than 30 μs (typical number). $\overline{\text{INVALID}}$ is low (invalid data) if all receiver input voltage are between –0.3 V and 0.3 V for more than 30 μs (typical number).

FUNCTION TABLE(1)

INPUT CONDITIONS				OUTPUT STATES				OPERATING MODE
FORCEON	$\overline{\text{FORCEOFF}}$	RECEIVER OR DRIVER EDGE WITHIN 30 s	VALID RS-232 LEVEL PRESENT AT RECEIVER	DRIVER	RECEIVER	$\overline{\text{INVALID}}$	READY	
Auto-Power-Down Plus Conditions								
H	H	No	No	Active	Active	L	H	Normal operation, auto-power-down plus disabled
H	H	No	Yes	Active	Active	H	H	Normal operation, auto-power-down plus disabled
L	H	Yes	No	Active	Active	L	H	Normal operation, auto-power-down plus enabled
L	H	Yes	Yes	Active	Active	H	H	Normal operation, auto-power-down plus enabled
L	H	No	No	Z	Active	L	L	Power down, auto-power-down plus enabled
L	H	No	Yes	Z	Active	H	L	Power down, auto-power-down plus enabled
X	L	X	No	Z	Active	L	L	Manual power down
X	L	X	Yes	Z	Active	H	L	Manual power down
Auto-Power-Down Conditions								
$\overline{\text{INVALID}}$	$\overline{\text{INVALID}}$	X	No	Z	Active	L	L	Power down, auto power down enabled
$\overline{\text{INVALID}}$	$\overline{\text{INVALID}}$	X	Yes	Active	Active	H	H	Normal operation, auto power down enabled

(1) H = high level, L = low level, X = irrelevant, Z = high impedance

LOGIC DIAGRAM (POSITIVE LOGIC)



TERMINAL FUNCTIONS

TERMINAL		DESCRIPTION
NAME	NO.	
C1+	2	Positive voltage-doubler charge-pump capacitor
C1–	4	Negative voltage-doubler charge-pump capacitor
C2+	5	Positive inverting charge-pump capacitor
C2–	6	Negative inverting charge-pump capacitor
DIN	12, 13	CMOS driver inputs
DOUT	8, 17	RS-232 driver outputs
$\overline{\text{FORCEOFF}}$	20	Force-off input, active low. Drive low to power down transmitters and charge pump. This overrides auto power down and FORCEON (see Function Table).
FORCEON	14	Force-on input, active high. Drive high to override auto power down, keeping transmitters on ($\overline{\text{FORCEOFF}}$ must be high) (see Function Table).
GND	18	Ground
$\overline{\text{INVALID}}$	11	Valid signal detector output, active low. A logic high indicates that a valid RS-232 level is present on a receiver input.
READY	1	Ready to transmit output, active high. READY is enabled high when V– goes below –3.5 V and the device is ready to transmit.
RIN	9, 16	RS-232 receiver inputs
ROUT	10, 15	CMOS receiver outputs
V+	3	2 × V_{CC} generated by the charge pump
V–	7	–2 × V_{CC} generated by the charge pump
V_{CC}	19	2.25-V to 3-V single-supply voltage

Absolute Maximum Ratings(1)

over operating free-air temperature range (unless otherwise noted)

		MIN	MAX	UNIT
V_{CC} to GND		–0.3	6	V
V+ to GND(2)		–0.3	7	V
V– to GND(2)		–7	0.3	V
V+ + IV-I(2)			13	V
Input voltage	DIN, FORCEON, $\overline{\text{FORCEOFF}}$ to GND	–0.3	6	V
	RIN to GND		±25	
Output voltage	DOUT to GND		±13.2	V
	ROUT, $\overline{\text{INVALID}}$, READY to GND	–0.3	V_{CC} + 0.3	
Short-circuit duration	DOUT to GND		Continuous	
Continuous power dissipation (T_A = 70°C)	16-pin SSOP (derate 7.14 mW/°C above 70°C)		571	mW
	20-pin SSOP (derate 8 mW/°C above 70°C		640	
	20-pin TSSOP (derate 7 mW/°C above 70°C)		559	
Storage temperature range		–65	150	°C
Lead temperature (soldering, 10 s)			300	°C

(1) Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

(2) V+ and V– can have maximum magnitudes of 7 V, but their absolute difference cannot exceed 13 V.

Recommended Operating Conditions

See Figure 4

				MIN	NOM	MAX	UNIT
	Supply voltage			2.25	2.5	3	V
V_{IH}	Driver and control high-level input voltage	DIN, $\overline{\text{FORCEOFF}}$, FORCEON	V_{CC} = 2.5 V to 3 V	0.7 × V_{CC}		5.5	V
V_{IL}	Driver and control low-level input voltage	DIN, $\overline{\text{FORCEOFF}}$, FORCEON	V_{CC} = 2.5 V to 3 V	0		0.3 × V_{CC}	V
V_I	Receiver input voltage			–25		25	V
T_A	Operating free-air temperature	MAX3318EC		0		70	°C
		MAX3318EI		–40		85	

Supply Current Section Electrical Characteristics

V_{CC} = 2.25 V to 3 V, C1–C4 = 0.1 µF, T_A = T_{MIN} to T_{MAX} (unless otherwise noted)

PARAMETER	TEST CONDITIONS	MIN	TYP(1)	MAX	UNIT
DC Characteristics (V_{CC} = 2.5 V, T_A = 25°C)					
Auto-power-down plus supply current	FORCEON = GND, $\overline{\text{FORCEOFF}}$ = V_{CC}, All RIN and DIN idle		1	10	µA
Auto-power-down supply current	$\overline{\text{FORCEOFF}}$ = GND		1	10	µA
Supply current	FORCEON = $\overline{\text{FORCEOFF}}$ = V_{CC}, No load		0.3	2	mA

(1) Typical values are at V_{CC} = 2.5 V, T_A = 25°C.

ESD Protection

PARAMETER	TEST CONDITIONS	TYP	UNIT
RIN, DOUT	HBM	±15	kV
	IEC 61000-4-2 Air-Gap Discharge method	±15	
	IEC 61000-4-2 Contact Discharge method	±8	

Driver Section Electrical Characteristics

over recommended ranges of supply voltage and operating free-air temperature,
V_{CC} = 2.25 V to 3 V, C1–C4 = 0.1 µF, T_A = T_{MIN} to T_{MAX} (unless otherwise noted) (see Figure 4)

PARAMETER	TEST CONDITIONS	MIN	TYP(1)	MAX	UNIT
Driver input hysteresis			0.3		V
Input leakage current	FORCEON, DIN, $\overline{\text{FORCEOFF}}$		±0.01	±1	µA
Output voltage swing	All driver outputs loaded with 3 kΩ to ground	±3.7	±4		V
Output resistance	V_{CC} = 0, Driver output = ±2 V	300	10M		Ω
Output short-circuit current(2)			±25	±60	mA
Output leakage current	V_{CC} = 0 or 2.25 V to 3 V, V_{OUT} = ±12 V, Drivers disabled			±25	µA

(1) Typical values are at V_{CC} = 2.5 V, T_A = 25°C.
(2) Short-circuit durations should be controlled to prevent exceeding the device absolute power dissipation ratings, and not more than one output should be shorted at a time.

Driver Section Switching Characteristics

over recommended ranges of supply voltage and operating free-air temperature,
V_{CC} = 2.25 V to 3 V, C1–C4 = 0.1 µF, T_A = T_{MIN} to T_{MAX} (unless otherwise noted) (see Figure 1)

PARAMETER	TEST CONDITIONS	MIN	TYP(1)	MAX	UNIT
Maximum data rate	R_L = 3 kΩ, C_L = 1000 pF, One transmitter switching	460			kbps
$\lvert t_{PHL} - t_{PLH} \rvert$ Driver skew(2)			100		ns
Transition-region slew rate	V_{CC} = 2.5 V, T_A = 25°C, R_L = 3 kΩ to 7 kΩ, Measured from 3 V to –3 V or –3 V to 3 V, C_L = 150 pF to 2500 pF	4		30	V/µs

(1) Typical values are at V_{CC} = 2.5 V, T_A = 25°C.
(2) Pulse skew is defined as $|t_{PLH} - t_{PHL}|$ of each channel of the same device.

Receiver Section Electrical Characteristics

over recommended ranges of supply voltage and operating free-air temperature,
V_{CC} = 2.25 V to 3 V, C1–C4 = 0.1 µF, T_A = T_{MIN} to T_{MAX} (unless otherwise noted) (see Figure 4)

PARAMETER	TEST CONDITIONS	MIN	TYP[1]	MAX	UNIT
Input voltage range		–25		25	V
Input threshold low	T_A = 25°C			0.3 × V_{CC}	V
Input threshold high	T_A = 25°C	0.7 × V_{CC}			V
Input hysteresis			0.3		V
Input resistance	T_A = 25°C	3	5	7	kΩ
Output leakage current			±0.05	±10	µA
Output voltage low	I_{OUT} = 0.5 mA			0.1 × V_{CC}	V
Output voltage high	I_{OUT} = –0.5 mA	0.9 × V_{CC}			V

(1) Typical values are at V_{CC} = 2.5 V, T_A = 25°C.

Receiver Section Switching Characteristics

over recommended ranges of supply voltage and operating free-air temperature,
V_{CC} = 2.25 V to 3 V, C1–C4 = 0.1 µF, T_A = T_{MIN} to T_{MAX} (unless otherwise noted) (see Figure 4)

PARAMETER		TEST CONDITIONS	TYP[1]	UNIT
t_{PHL}	Receiver propagation delay	RIN to ROUT, C_L = 150 pF	0.175	µs
t_{PLH}			0.175	
$\lvert t_{PHL} - t_{PLH}\rvert$	Receiver skew[2]		50	ns

(1) Typical values are at V_{CC} = 2.5 V, T_A = 25°C.
(2) Pulse skew is defined as $\lvert t_{PLH} - t_{PHL}\rvert$ of each channel of the same device.

Auto-Power-Down Plus Section Electrical Characteristics

over recommended ranges of supply voltage and operating free-air temperature,
V_{CC} = 2.25 V to 3 V, C1–C4 = 0.1 µF, T_A = T_{MIN} to T_{MAX} (unless otherwise noted) (see Figure 4)

PARAMETER	TEST CONDITIONS	MIN	MAX	UNIT
Receiver input threshold to $\overline{\text{INVALID}}$ high	Positive threshold		2.7	V
	Negative threshold	–2.7		
Receiver input threshold $\overline{\text{INVALID}}$ low		–0.3	0.3	V
$\overline{\text{INVALID}}$, READY voltage low	I_{OUT} = 0.5 mA		0.1 × V_{CC}	V
$\overline{\text{INVALID}}$, READY voltage high	I_{OUT} = –0.5 mA	0.8 × V_{CC}		V

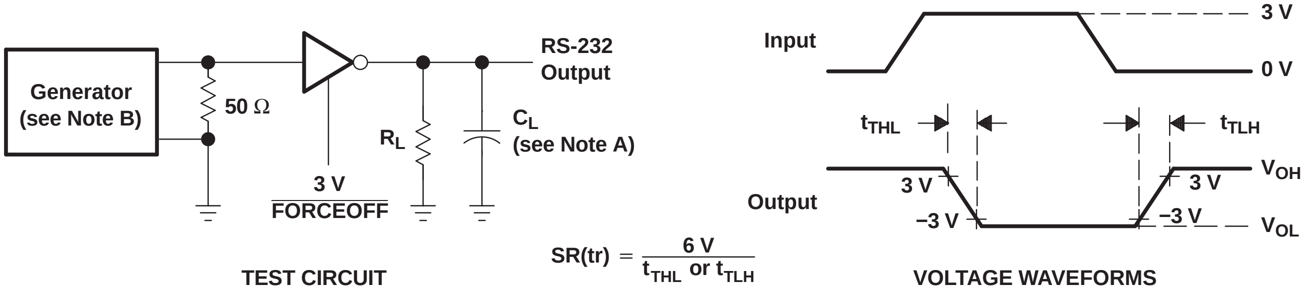
Auto-Power-Down Plus Section Switching Characteristics

over recommended ranges of supply voltage and operating free-air temperature,
V_{CC} = 2.25 V to 3 V, C1–C4 = 0.1 µF, T_A = T_{MIN} to T_{MAX} (unless otherwise noted) (see Figure 4)

PARAMETER		TEST CONDITIONS	MIN	TYP[1]	MAX	UNIT
t_{INVH}	Receiver positive or negative threshold to $\overline{\text{INVALID}}$ high	V_{CC} = 2.5 V		1		µs
t_{INVL}	Receiver positive or negative threshold to $\overline{\text{INVALID}}$ low	V_{CC} = 2.5 V		30		µs
t_{WU}	Receiver or driver edge to driver enabled	V_{CC} = 2.5 V		100		µs
$t_{AUTOPRDN}$	Receiver or driver edge to driver shutdown	V_{CC} = 2.5 V	15	30	60	s

(1) Typical values are at V_{CC} = 2.5 V, T_A = 25°C.

PARAMETER MEASUREMENT INFORMATION



$$SR(tr) = \frac{6\ V}{t_{THL}\ or\ t_{TLH}}$$

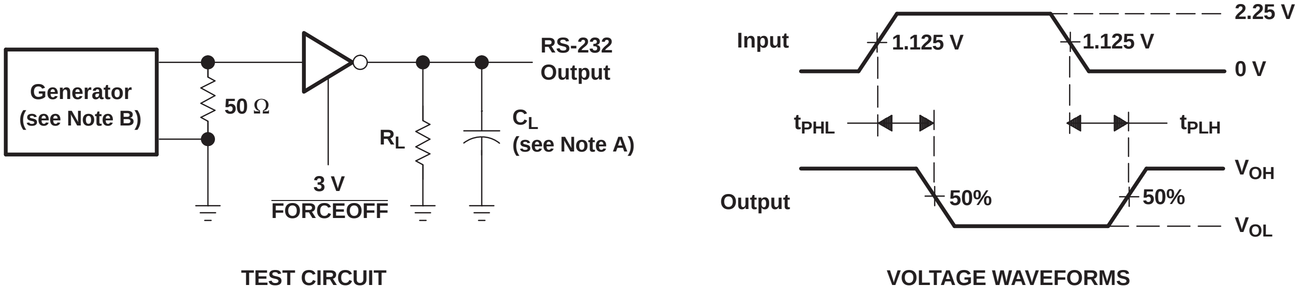
TEST CIRCUIT

VOLTAGE WAVEFORMS

NOTES: A. C_L includes probe and jig capacitance.

B. The pulse generator has the following characteristics: PRR = 250 kbit/s, Z_O = 50 Ω, 50% duty cycle, $t_r \leq 10$ ns, $t_f \leq 10$ ns.

Figure 1. Driver Slew Rate



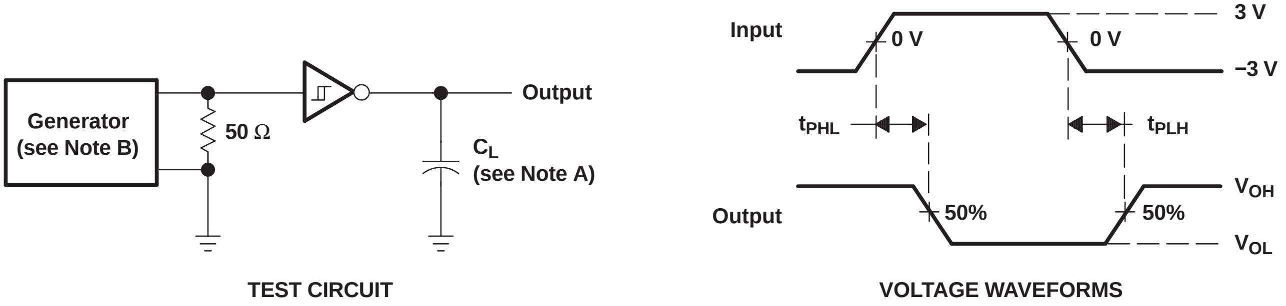
TEST CIRCUIT

VOLTAGE WAVEFORMS

NOTES: A. C_L includes probe and jig capacitance.

B. The pulse generator has the following characteristics: PRR = 250 kbit/s, Z_O = 50 Ω, 50% duty cycle, $t_r \leq 10$ ns, $t_f \leq 10$ ns.

Figure 2. Driver Pulse Skew



TEST CIRCUIT

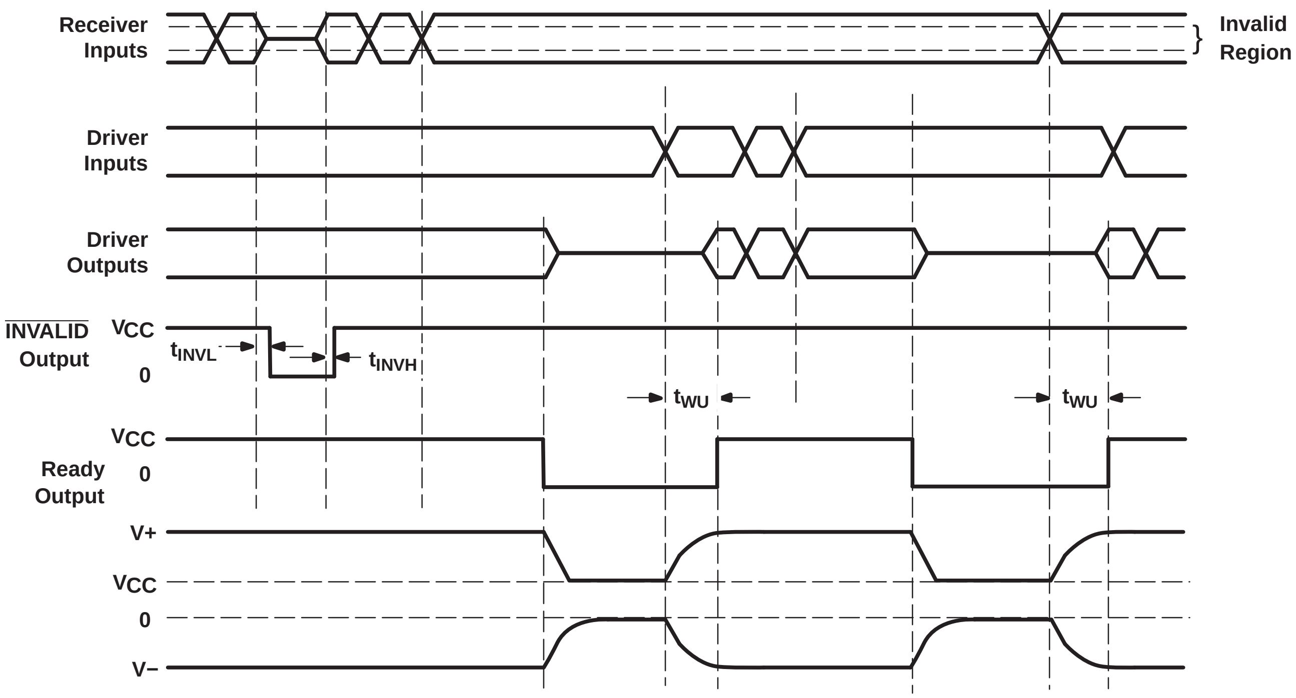
VOLTAGE WAVEFORMS

NOTES: A. C_L includes probe and jig capacitance.

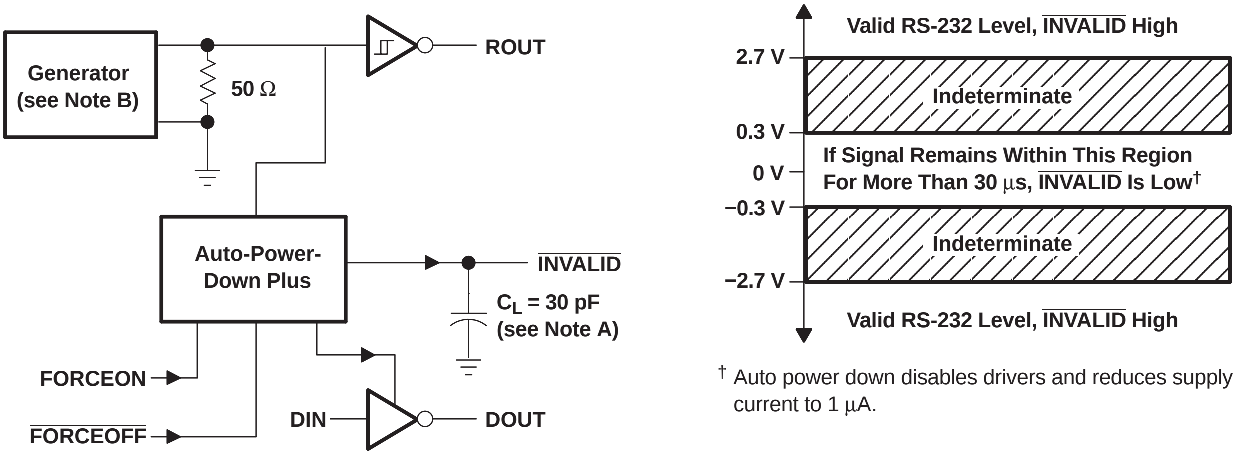
B. The pulse generator has the following characteristics: Z_O = 50 Ω, 50% duty cycle, $t_r \leq 10$ ns, $t_f \leq 10$ ns.

Figure 3. Receiver Propagation Delay Times

PARAMETER MEASUREMENT INFORMATION



VOLTAGE WAVEFORMS



† Auto power down disables drivers and reduces supply current to 1 µA.

TEST CIRCUIT

Figure 4. $\overline{\text{INVALID}}$ Propagation Delay Times and Supply Enabling Time

PARAMETER MEASUREMENT INFORMATION

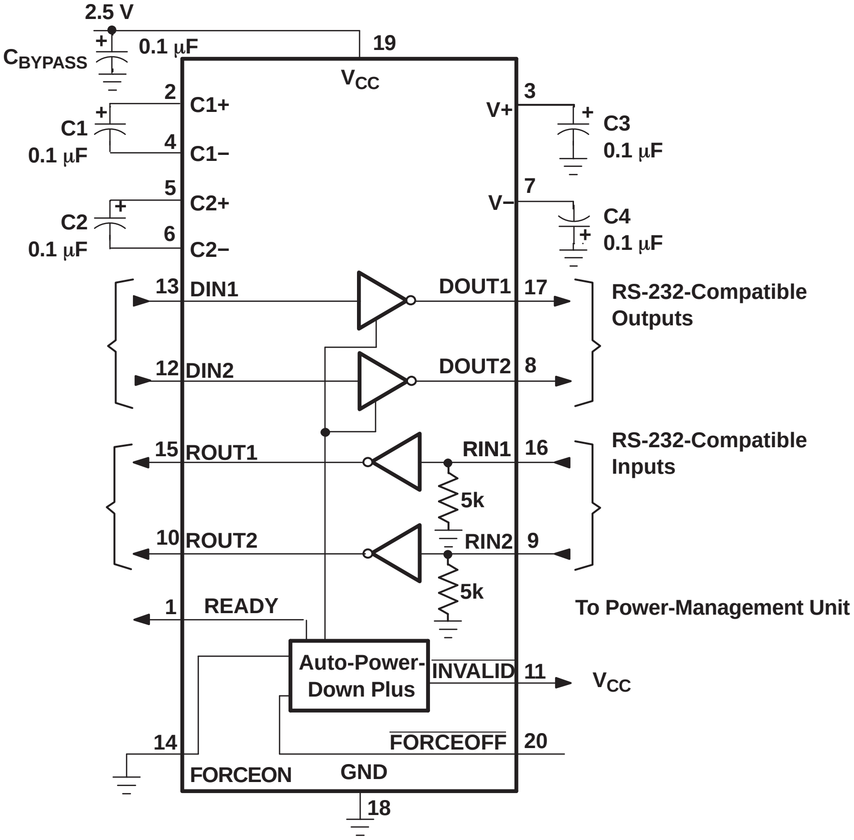


Figure 5. Typical Application Circuit

REVISION HISTORY

Changes from Original (June 2006) to Revision A	**Page**
• Updated document to new TI datasheet format - no specification changes.	1
• Removed Ordering Information Table.	2
• Updated TERMINAL FUNCTIONS table to fix inconsistency.	3

PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead/Ball Finish	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
MAX3318ECDB	ACTIVE	SSOP	DB	20	70	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	MP318EC	Samples
MAX3318ECDBG4	ACTIVE	SSOP	DB	20	70	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	MP318EC	Samples
MAX3318ECDBR	ACTIVE	SSOP	DB	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	MP318EC	Samples
MAX3318ECDBRG4	ACTIVE	SSOP	DB	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	MP318EC	Samples
MAX3318ECPW	ACTIVE	TSSOP	PW	20	70	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	MP318EC	Samples
MAX3318ECPWG4	ACTIVE	TSSOP	PW	20	70	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	MP318EC	Samples
MAX3318ECPWR	ACTIVE	TSSOP	PW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	MP318EC	Samples
MAX3318ECPWRG4	ACTIVE	TSSOP	PW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	MP318EC	Samples
MAX3318EIDB	ACTIVE	SSOP	DB	20	70	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	MP318EI	Samples
MAX3318EIDBG4	ACTIVE	SSOP	DB	20	70	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	MP318EI	Samples
MAX3318EIDBR	ACTIVE	SSOP	DB	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	MP318EI	Samples
MAX3318EIDBRG4	ACTIVE	SSOP	DB	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	MP318EI	Samples
MAX3318EIPW	ACTIVE	TSSOP	PW	20	70	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	MP318EI	Samples
MAX3318EIPWG4	ACTIVE	TSSOP	PW	20	70	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	MP318EI	Samples
MAX3318EIPWR	ACTIVE	TSSOP	PW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	MP318EI	Samples
MAX3318EIPWRG4	ACTIVE	TSSOP	PW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	MP318EI	Samples

[1] The marketing status values are defined as follows:
ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.
NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.
PREVIEW: Device has been announced but is not in production. Samples may or may not be available.
OBSOLETE: TI has discontinued the production of the device.

[2] Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.
TBD: The Pb-Free/Green conversion plan has not been defined.
Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.
Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.
Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

[3] MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

[4] There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

[5] Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

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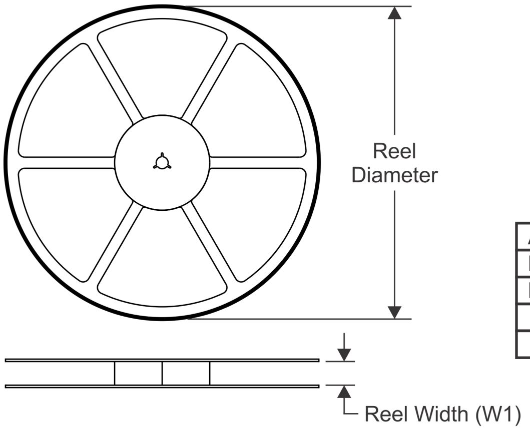
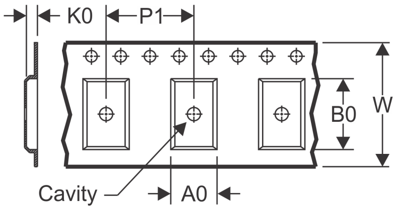
TAPE AND REEL INFORMATION

REEL DIMENSIONS

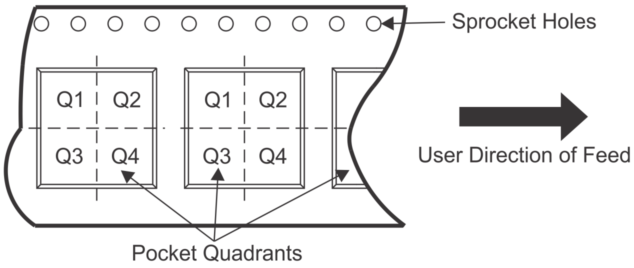


TAPE DIMENSIONS



A0	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

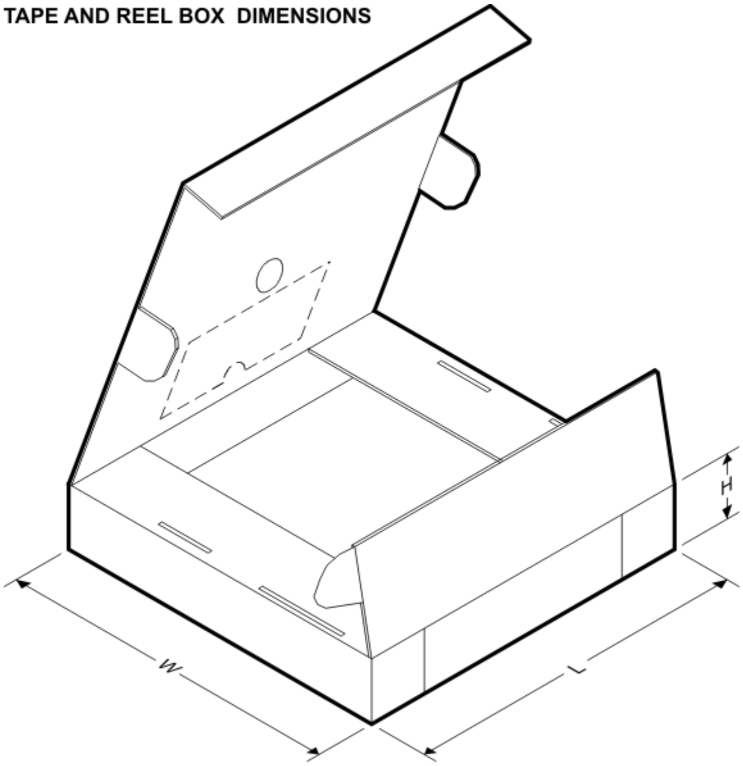
QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
MAX3318ECDBR	SSOP	DB	20	2000	330.0	16.4	8.2	7.5	2.5	12.0	16.0	Q1
MAX3318ECPWR	TSSOP	PW	20	2000	330.0	16.4	6.95	7.1	1.6	8.0	16.0	Q1
MAX3318EIDBR	SSOP	DB	20	2000	330.0	16.4	8.2	7.5	2.5	12.0	16.0	Q1
MAX3318EIPWR	TSSOP	PW	20	2000	330.0	16.4	6.95	7.1	1.6	8.0	16.0	Q1

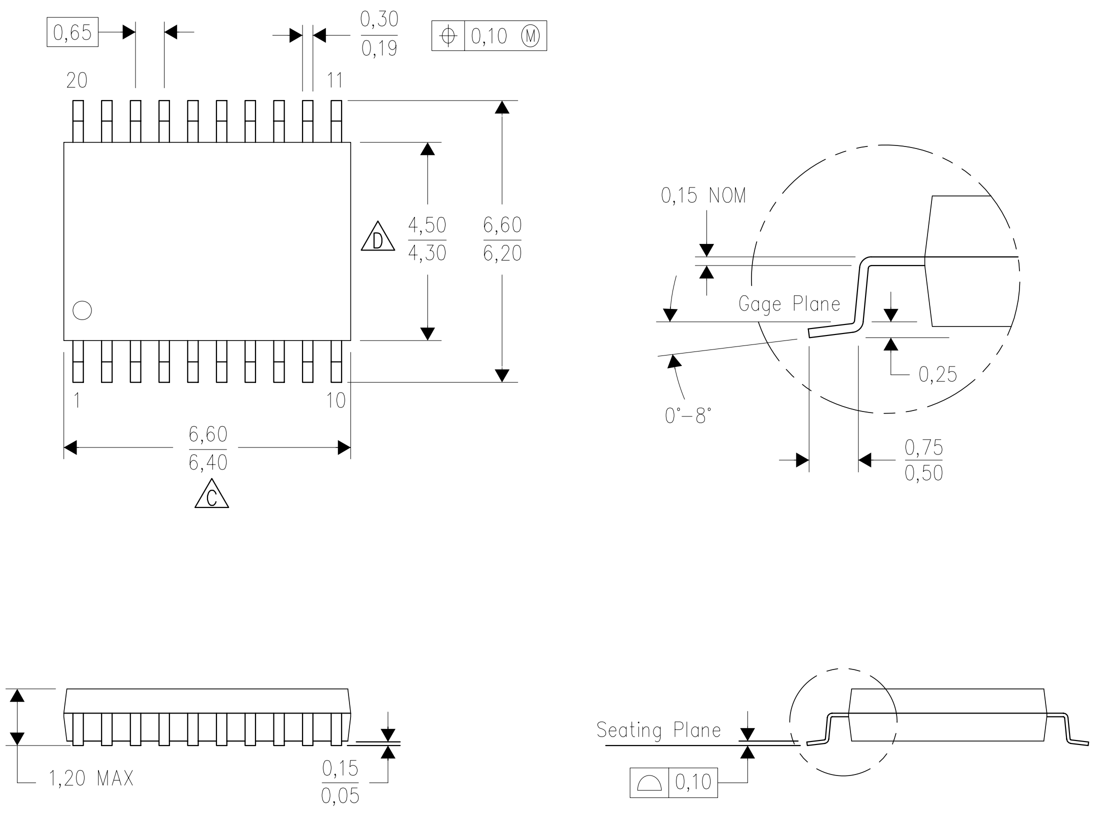
TAPE AND REEL BOX DIMENSIONS



*All dimensions are nominal

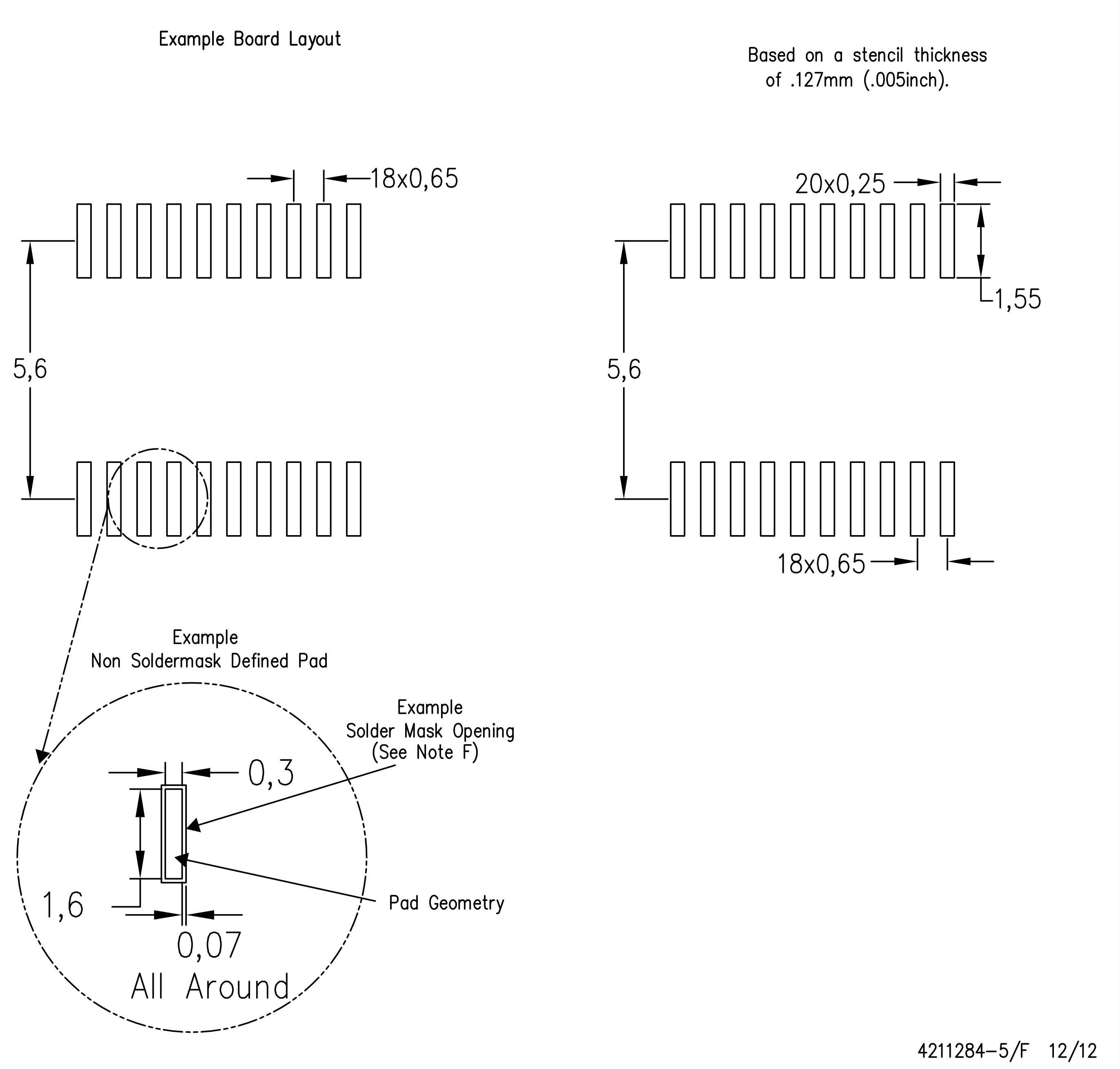
Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
MAX3318ECDBR	SSOP	DB	20	2000	367.0	367.0	38.0
MAX3318ECPWR	TSSOP	PW	20	2000	367.0	367.0	38.0
MAX3318EIDBR	SSOP	DB	20	2000	367.0	367.0	38.0
MAX3318EIPWR	TSSOP	PW	20	2000	367.0	367.0	38.0

PW (R-PDSO-G20) PLASTIC SMALL OUTLINE



NOTES:
- A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M–1994.
- B. This drawing is subject to change without notice.
- △C Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0,15 each side.
- △D Body width does not include interlead flash. Interlead flash shall not exceed 0,25 each side.
- E. Falls within JEDEC MO–153

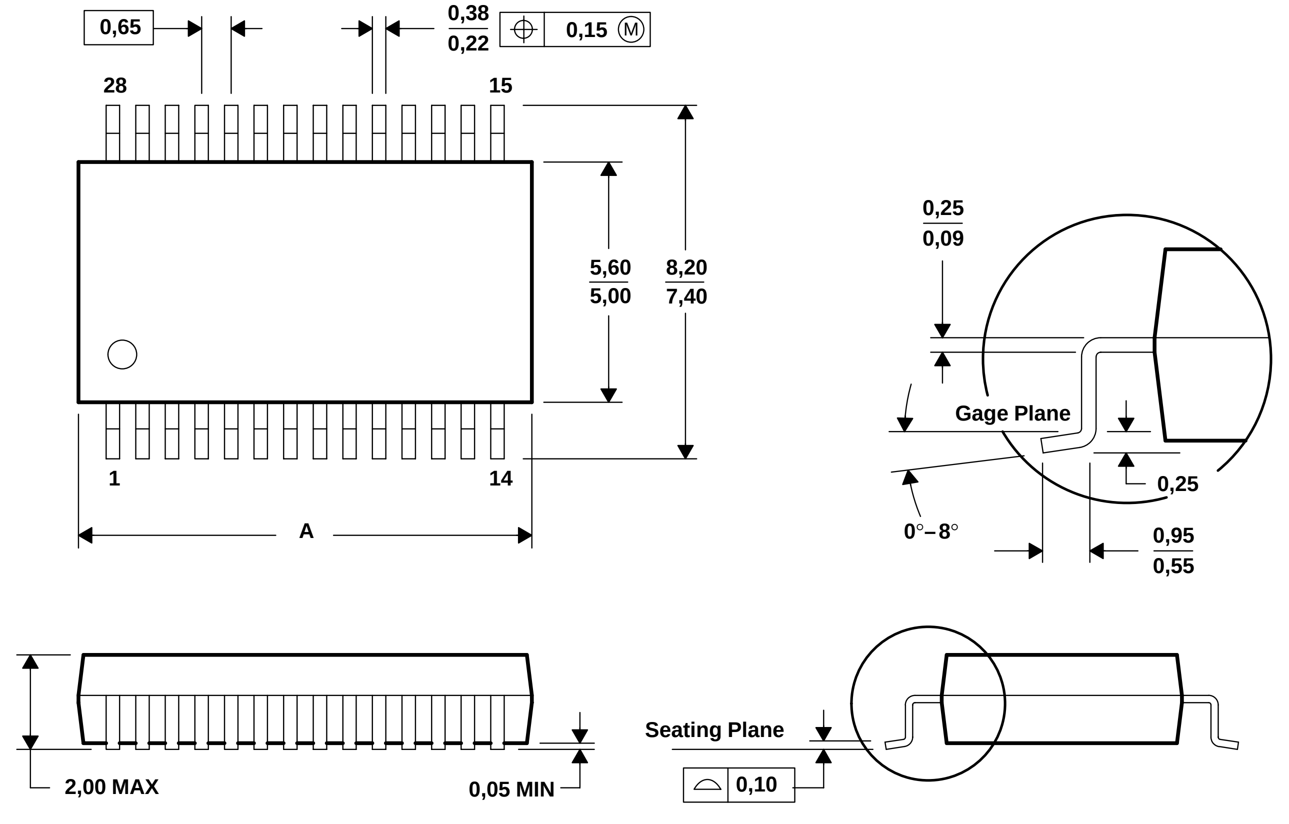
PW (R–PDSO–G20) PLASTIC SMALL OUTLINE



NOTES:
- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Publication IPC–7351 is recommended for alternate design.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC–7525 for other stencil recommendations.
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.

DB (R-PDSO-G**) PLASTIC SMALL-OUTLINE

28 PINS SHOWN



PINS ** / DIM	14	16	20	24	28	30	38
A MAX	6,50	6,50	7,50	8,50	10,50	10,50	12,90
A MIN	5,90	5,90	6,90	7,90	9,90	9,90	12,30

4040065 /E 12/01

NOTES:
- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion not to exceed 0,15.
- D. Falls within JEDEC MO-150

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